

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Darlington

2SB1351



Silicon PNP Epitaxial Planar Transistor

Application: Driver for Printer Head, Solenoid, Relay, Motor and General Purpose

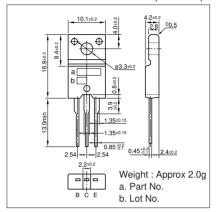
■Abs	olute	maximum ratings	(Ta=25°C)
			T

Symbol	Ratings	Unit	
Vсво	-60	V	
VCEO	-60	V	
VEBO	-6	V	
Ic	-12(Pulse-20)	Α	
Ів	-1	Α	
Pc	30(Tc=25°C)	W	
Tj	150	°C	
Tstg	Tstg -55 to +150		

■Electrical Characteristics

■Electrical	(Ta	(Ta=25°C)	
Symbol	Condition	Ratings	Unit
Ісво	Vcb=-60V	-10max	μΑ
І ЕВО	VEB=-6V	-10max	mA
V(BR)CEO	Ic=-10mA	-60min	V
hfE	Vce=-4V, Ic=-10A	2000min	
VcE(sat)	Ic=-10A, IB=-20mA	nA -1.5max	
V _{BE} (sat)	Ic=-10A, IB=-20mA	-2.0max	V
fτ	Vce=-12V, Ie=1A	130typ	MHz
Сов	VcB=-10V, f=1MHz 170typ		pF

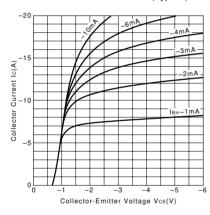
External Dimensions FM20(TO220F)



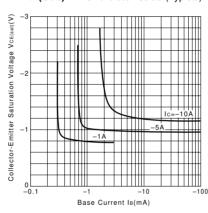
■Typical Switching Characteristics (Common Emitter)

Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (mA)	I _{B2} (mA)	ton (µs)	tstg (µs)	tf (μs)
-40	4	-10	-10	5	-20	20	0.7typ	1.5typ	0.6typ

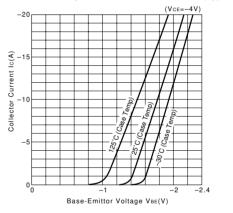
Ic-VcE Characteristics (Typical)



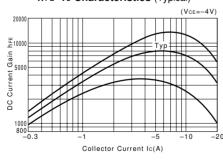
VcE(sat)-IB Characteristics (Typical)



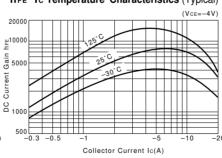
Ic-VBE Temperature Characteristics (Typical)



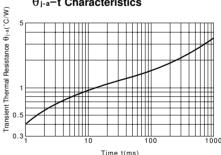
hfe-Ic Characteristics (Typical)



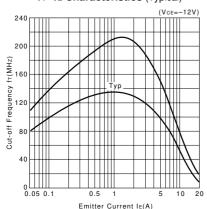
hfe-Ic Temperature Characteristics (Typical)



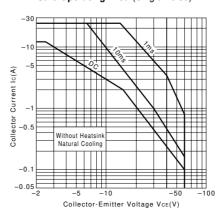
θ_{j-a}-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

